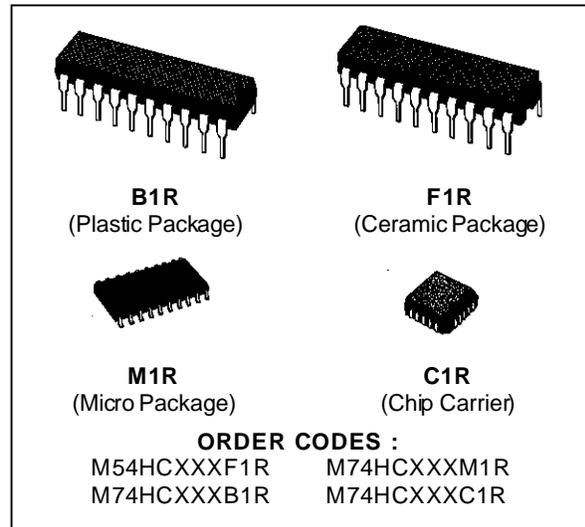


OCTAL BUS TRANSCEIVER HC620 3 STATE INVERTING HC623 3 STATE NON INVERTING

- HIGH SPEED
 $t_{PD} = 10 \text{ ns (TYP.) AT } V_{CC} = 5 \text{ V}$
- LOW POWER DISSIPATION
 $I_{CC} = 4 \mu\text{A (MAX.) AT } T_A = 25 \text{ }^\circ\text{C}$
- HIGH NOISE IMMUNITY
 $V_{NIH} = V_{NIL} = 28 \% V_{CC} \text{ (MIN.)}$
- OUTPUT DRIVE CAPABILITY
 15 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE
 $|I_{OH}| = I_{OL} = 6 \text{ mA (MIN.)}$
- BALANCED PROPAGATION DELAYS
 $t_{PLH} = t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE
 $V_{CC} \text{ (OPR)} = 2 \text{ V to } 6 \text{ V}$
- PIN AND FUNCTION COMPATIBLE
 WITH LS620/623



DESCRIPTION

The M54/74HC620/623 are high speed CMOS OCTAL BUS TRANSCEIVERS fabricated in silicon gate C²MOS technology. They have the same high speed performance of LSTTL combined with true CMOS low power consumption.

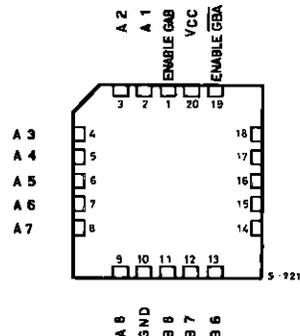
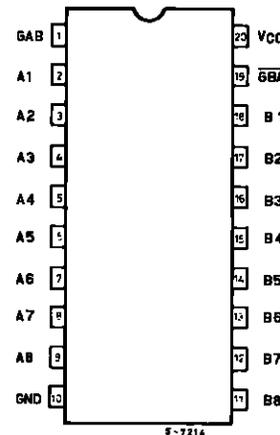
These octal bus transceivers are designed for asynchronous two-way communication between data buses. The control function implementation allows maximum flexibility in timing.

These devices allow data transmission from the A bus to B bus or from the B to the A bus depending upon the logic levels at the enable inputs (GBA and GAB). The enable inputs can be used to disable the device so that the buses are effectively isolated.

The dual-enable configuration gives these devices the capability to store data by simultaneous enabling of GBA and GAB.

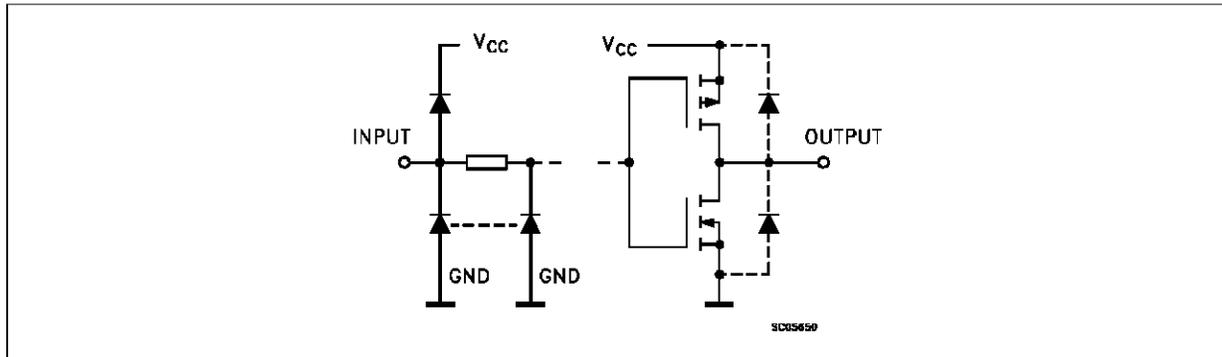
Each output reinforces its input in this transceiver configuration. Thus, when both control inputs are enabled and all other data sources to the two sets of bus lines are at high impedance, both sets of bus lines (16 in all) will remain at their last states. The 8-bit codes appearing on the two sets of buses will be identical for the 'HC623 or complementary for the 'HC620. All inputs are equipped with protection circuits against static discharge and transient excess voltage.

PIN CONNECTIONS (top view)



NC =
No Internal
Connection

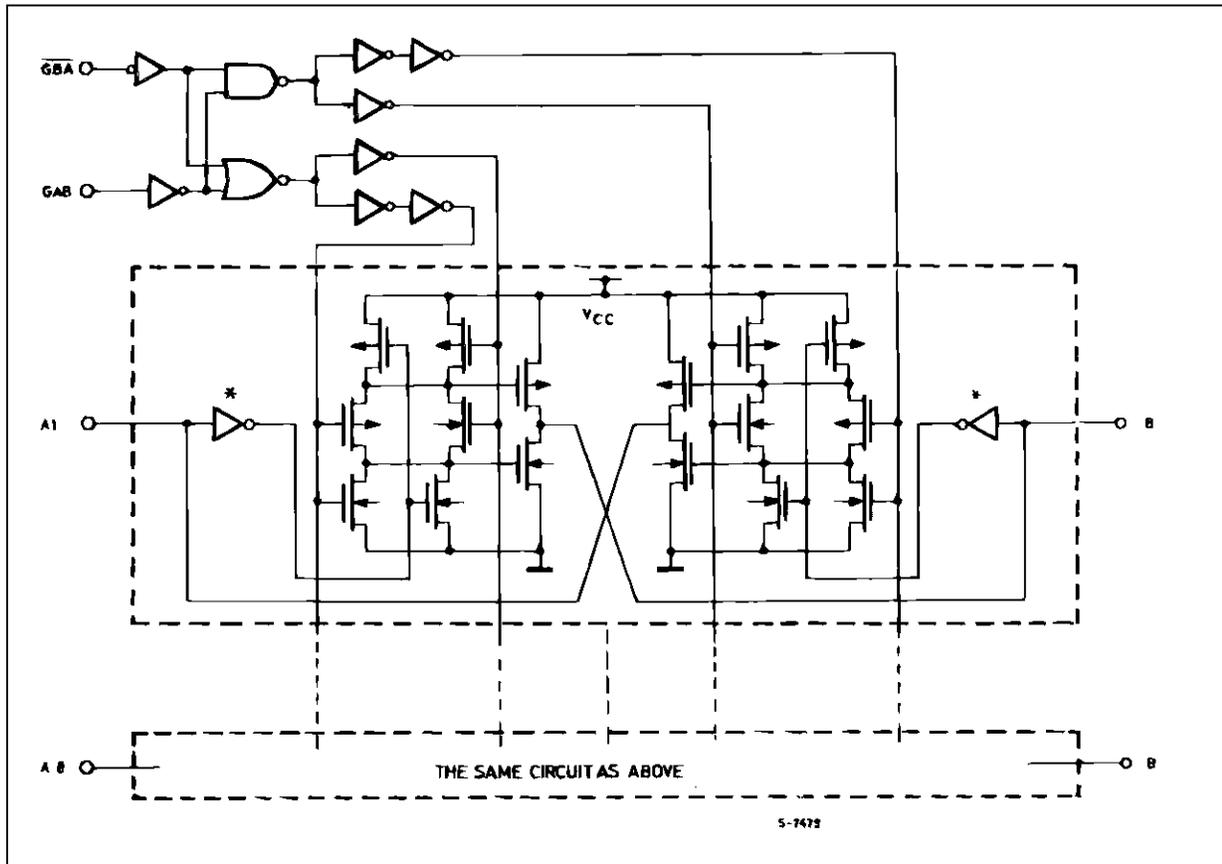
INPUT AND OUTPUT EQUIVALENT CIRCUIT



TRUTH TABLE

| INPUTS | | FUNCTION | | OUTPUTS | |
|--------|------------------|----------------|--------|--------------------|---------|
| GAB | \overline{GAB} | A Bus | B Bus | HC620 | HC623 |
| L | L | Output | Input | $A = \overline{B}$ | $A = B$ |
| H | H | Input | Output | $B = \overline{A}$ | $B = A$ |
| L | H | High Impedance | | Z | Z |
| H | L | High Impedance | | Z | Z |

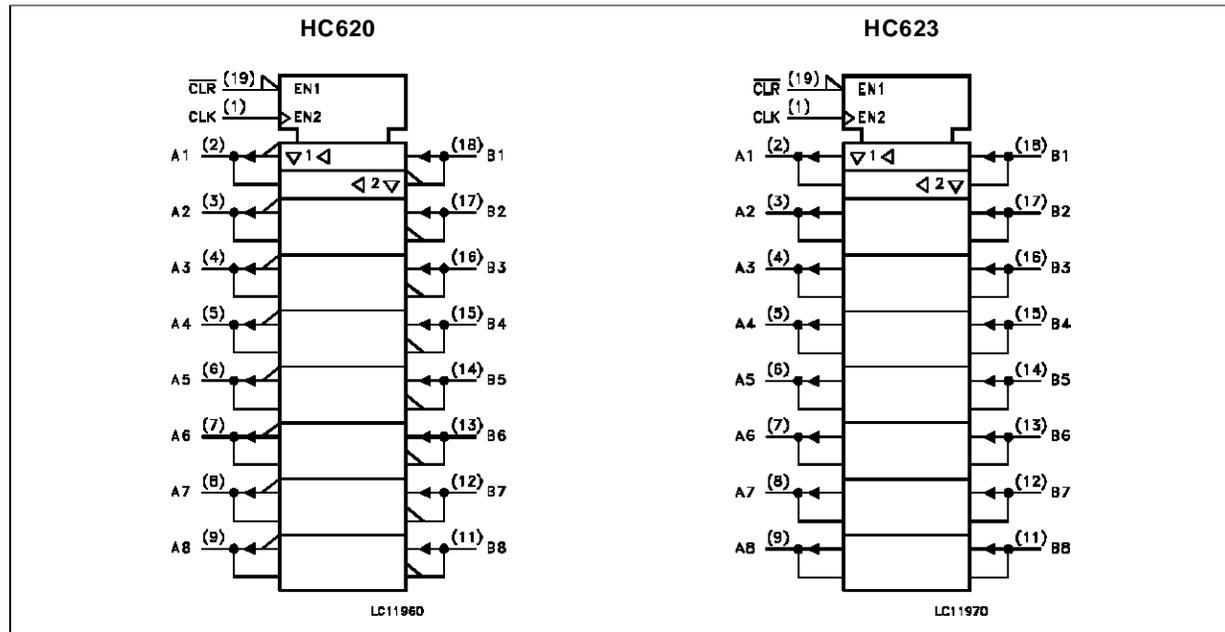
LOGIC DIAGRAM



PIN DESCRIPTION

| PIN No | SYMBOL | NAME AND FUNCTION |
|--------------------------------|-------------------------------|-------------------------|
| 1, 19 | $\overline{\text{GBA}}$, GAB | Direction Controls |
| 2, 3, 4, 5, 6, 7, 8, 9 | A1 to A8 | Data Inputs/Outputs |
| 11, 12, 13, 14, 15, 16, 17, 18 | B1 to B8 | Data Inputs/Outputs |
| 10 | GND | Ground (0V) |
| 20 | V _{CC} | Positive Supply Voltage |

IEC LOGIC SYMBOLS



ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-------------------------------------|--|-------------------------------|------|
| V _{CC} | Supply Voltage | -0.5 to +7 | V |
| V _I | DC Input Voltage | -0.5 to V _{CC} + 0.5 | V |
| V _O | DC Output Voltage | -0.5 to V _{CC} + 0.5 | V |
| I _{IK} | DC Input Diode Current | ± 20 | mA |
| I _{OK} | DC Output Diode Current | ± 20 | mA |
| I _O | DC Output Source Sink Current Per Output Pin | ± 35 | mA |
| I _{CC} or I _{GND} | DC V _{CC} or Ground Current | ± 70 | mA |
| P _D | Power Dissipation | 500 (*) | mW |
| T _{stg} | Storage Temperature | -65 to +150 | °C |
| T _L | Lead Temperature (10 sec) | 300 | °C |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.
 (*) 500 mW: ≡ 65 °C derate to 300 mW by 10mW/°C: 65 °C to 85 °C

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Value | Unit | |
|------------|---|---------------------------|-----------|----|
| V_{CC} | Supply Voltage | 2 to 6 | V | |
| V_I | Input Voltage | 0 to V_{CC} | V | |
| V_O | Output Voltage | 0 to V_{CC} | V | |
| T_{op} | Operating Temperature: M54HC Series M74HC Series | -55 to +125 -40 to +85 | °C °C | |
| t_r, t_f | Input Rise and Fall Time | $V_{CC} = 2\text{ V}$ | 0 to 1000 | ns |
| | | $V_{CC} = 4.5\text{ V}$ | 0 to 500 | |
| | | $V_{CC} = 6\text{ V}$ | 0 to 400 | |

DC SPECIFICATIONS

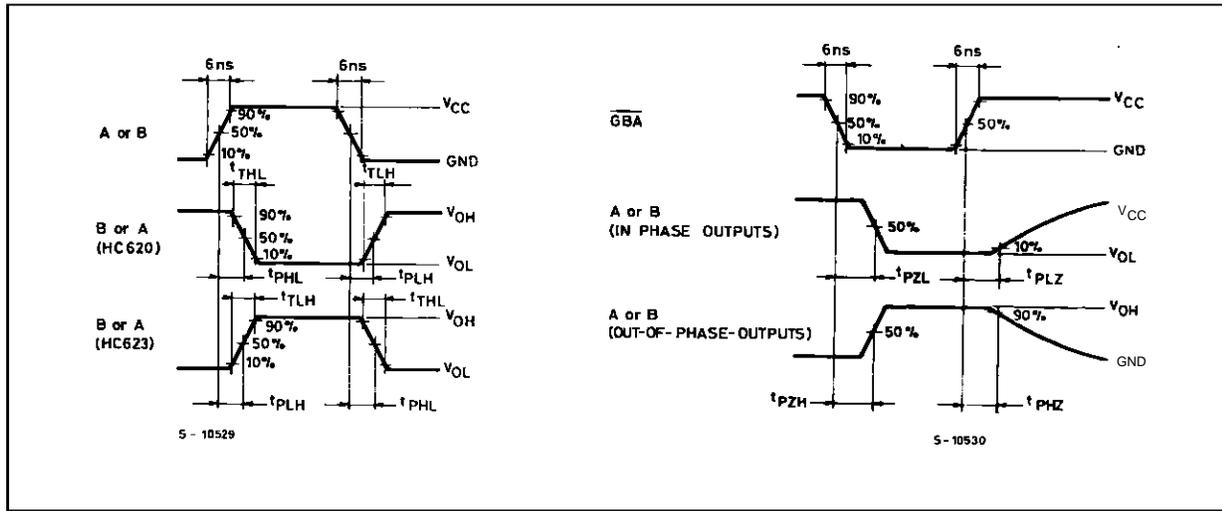
| Symbol | Parameter | Test Conditions | | Value | | | | | | Unit | | |
|----------|----------------------------------|----------------------------------|---|---------------------------------------|------|-----------|--------------------------------------|---------|---------------------------------------|----------|---------------|---|
| | | | | $T_A = 25\text{ °C}$ 54HC and 74HC | | | $-40\text{ to }85\text{ °C}$ 74HC | | $-55\text{ to }125\text{ °C}$ 54HC | | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | Max. | |
| V_{IH} | High Level Input Voltage | V_{CC} (V) | | | | | | | | | V | |
| | | 2.0 | | | 1.5 | | | 1.5 | | 1.5 | | |
| | | 4.5 | | | 3.15 | | | 3.15 | | 3.15 | | |
| V_{IL} | Low Level Input Voltage | 2.0 | | | | | 0.5 | | 0.5 | | 0.5 | V |
| | | 4.5 | | | | | 1.35 | | 1.35 | | 1.35 | |
| | | 6.0 | | | | | 1.8 | | 1.8 | | 1.8 | |
| V_{OH} | High Level Output Voltage | $V_I = V_{IH}$ or V_{IL} | $I_O = -20\text{ }\mu\text{A}$ | 2.0 | 1.9 | 2.0 | | 1.9 | | 1.9 | | V |
| | | | | 4.5 | 4.4 | 4.5 | | 4.4 | | 4.4 | | |
| | | | | 6.0 | 5.9 | 6.0 | | 5.9 | | 5.9 | | |
| | | | 4.5 | 4.18 | 4.31 | | 4.13 | | 4.10 | | | |
| | | | 6.0 | 5.68 | 5.8 | | 5.63 | | 5.60 | | | |
| V_{OL} | Low Level Output Voltage | $V_I = V_{IH}$ or V_{IL} | $I_O = 20\text{ }\mu\text{A}$ | 2.0 | | 0.0 | 0.1 | | 0.1 | | 0.1 | V |
| | | | | 4.5 | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | | | 6.0 | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | | 4.5 | | 0.17 | 0.26 | | 0.33 | | 0.40 | | |
| | | | 6.0 | | 0.18 | 0.26 | | 0.33 | | 0.40 | | |
| I_I | Input Leakage Current | 6.0 | $V_I = V_{CC}$ or GND | | | ± 0.1 | | ± 1 | | ± 1 | μA | |
| I_{OZ} | 3 State Output Off State Current | 6.0 | $V_I = V_{IH}$ or V_{IL} $V_O = V_{CC}$ or GND | | | ± 0.5 | | ± 5 | | ± 10 | μA | |
| I_{CC} | Quiescent Supply Current | 6.0 | $V_I = V_{CC}$ or GND | | | 4 | | 40 | | 80 | μA | |

AC ELECTRICAL CHARACTERISTICS ($C_L = 50$ pF, Input $t_r = t_f = 6$ ns)

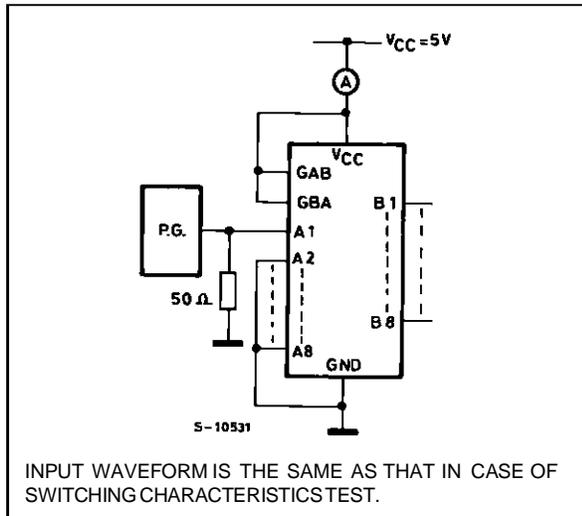
| Symbol | Parameter | Test Conditions | | | Value | | | | | | Unit | |
|--------------------------------------|---------------------------------------|------------------------|------------------------|------------------------|---|----------|------|----------------------|------|-----------------------|------|------|
| | | V _{CC} (V) | C _L (pF) | | T _A = 25 °C 54HC and 74HC | | | -40 to 85 °C 74HC | | -55 to 125 °C 54HC | | |
| | | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | Max. |
| t _{TLH} t _{THL} | Output Transition Time | 2.0 | 50 | | | 25 | 60 | | 75 | | 90 | ns |
| | | 4.5 | | | 7 | 12 | | 15 | | 18 | | |
| | | 6.0 | | | 6 | 10 | | 13 | | 15 | | |
| t _{PLH} t _{PHL} | Propagation Delay Time (for HC620) | 2.0 | 50 | | 41 | 100 | | 125 | | 150 | ns | |
| | | 4.5 | | | 12 | 20 | | 25 | | 30 | | |
| | | 6.0 | | | 10 | 17 | | 21 | | 26 | | |
| | | 2.0 | 150 | | 55 | 130 | | 165 | | 195 | ns | |
| | | 4.5 | | | 16 | 26 | | 33 | | 39 | | |
| | | 6.0 | | | 14 | 22 | | 28 | | 33 | | |
| t _{PLH} t _{PHL} | Propagation Delay Time (for HC623) | 2.0 | 50 | | 38 | 85 | | 105 | | 130 | ns | |
| | | 4.5 | | | 12 | 17 | | 21 | | 26 | | |
| | | 6.0 | | | 10 | 14 | | 18 | | 22 | | |
| | | 2.0 | 150 | | 51 | 130 | | 165 | | 195 | ns | |
| | | 4.5 | | | 16 | 26 | | 33 | | 39 | | |
| | | 6.0 | | | 14 | 22 | | 28 | | 33 | | |
| t _{PZL} t _{PZH} | Output Enable Time | 2.0 | 50 | R _L = 1 KΩ | | 57 | 150 | | 190 | | 225 | ns |
| | | 4.5 | | | | 19 | 30 | | 38 | | 45 | |
| | | 6.0 | | | | 16 | 26 | | 32 | | 38 | |
| | | 2.0 | 150 | R _L = 1 KΩ | | 69 | 180 | | 225 | | 270 | ns |
| | | 4.5 | | | | 23 | 36 | | 45 | | 54 | |
| | | 0 | | | | 20 | 31 | | 38 | | 46 | |
| t _{PLZ} t _{PHZ} | Output Disable Time | 2.0 | 50 | R _L = 1 KΩ | | 43 | 125 | | 155 | | 190 | ns |
| | | 4.5 | | | | 18 | 25 | | 31 | | 38 | |
| | | 6.0 | | | | 15 | 21 | | 26 | | 32 | |
| C _{IN} | Input Capacitance | | | | | 5 | 10 | | 10 | | 10 | pF |
| C _{PD} (*) | Power Dissipation Capacitance | | | for HC620 for HC623 | | 32 34 | | | | | | pF |

C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

SWITCHING CHARACTERISTICS TEST WAVEFORM



TEST CIRCUIT I_{CC} (Opr.)



C_{PD} CALCULATION

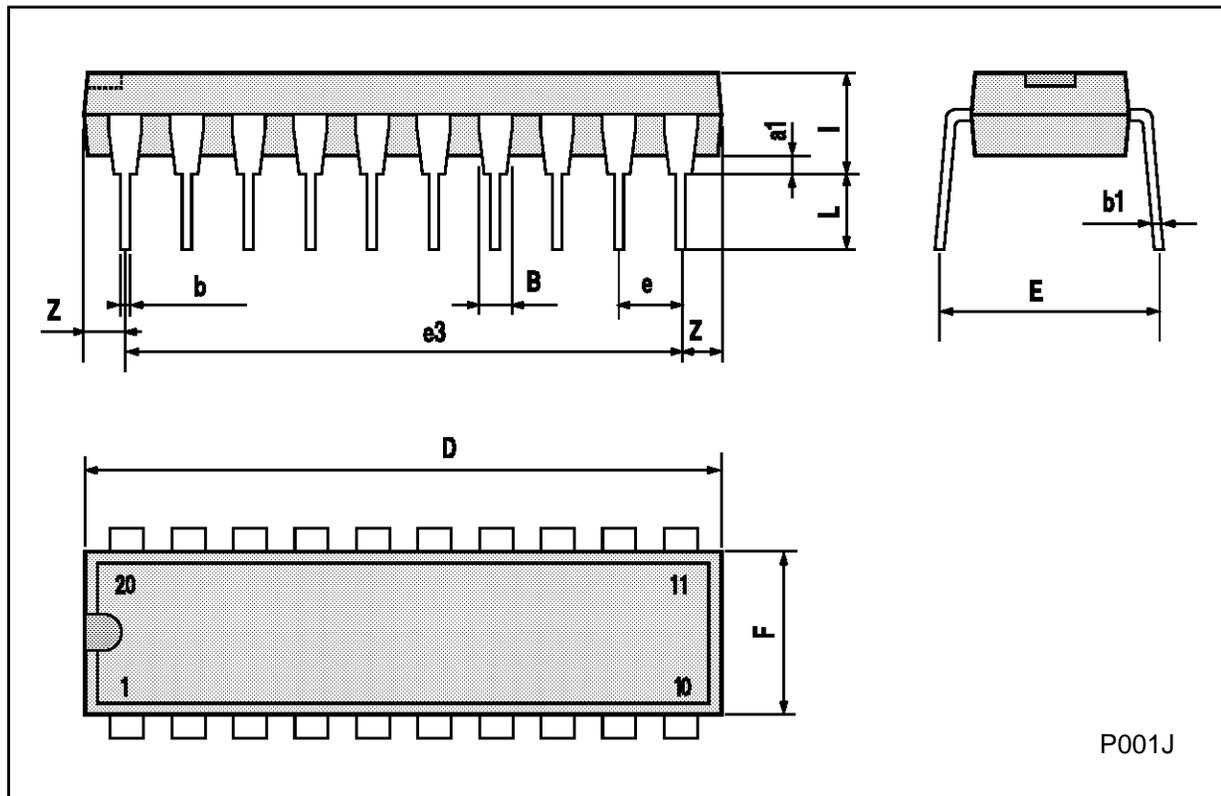
C_{PD} is to be calculated with the following formula by using the measured value of I_{CC} (Opr.) in the test circuit opposite.

$$C_{PD} = \frac{I_{CC} (Opr.)}{f_{IN} \times V_{CC}}$$

In determining the typical value of C_{PD} , a relatively high frequency of 1 MHz was applied to f_{IN} , in order to eliminate any error caused by the quiescent supply current.

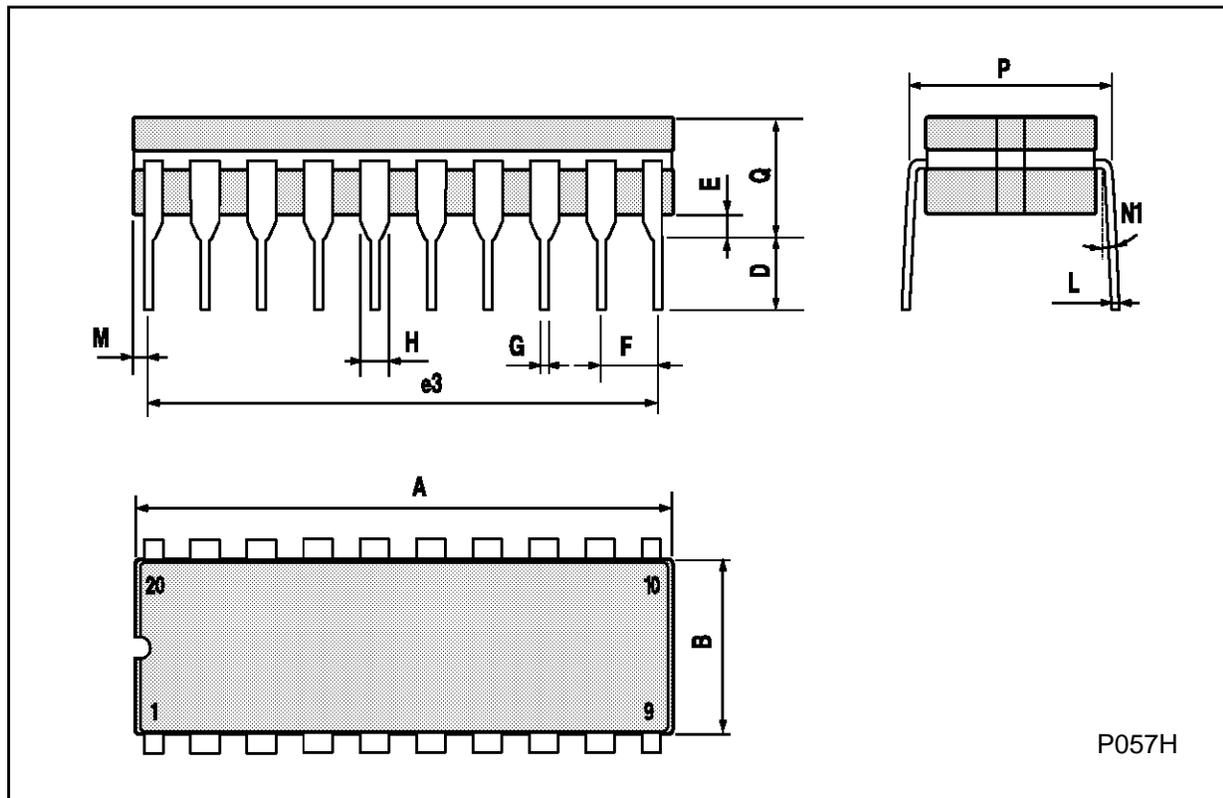
Plastic DIP20 (0.25) MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|-------|-------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| a1 | 0.254 | | | 0.010 | | |
| B | 1.39 | | 1.65 | 0.055 | | 0.065 |
| b | | 0.45 | | | 0.018 | |
| b1 | | 0.25 | | | 0.010 | |
| D | | | 25.4 | | | 1.000 |
| E | | 8.5 | | | 0.335 | |
| e | | 2.54 | | | 0.100 | |
| e3 | | 22.86 | | | 0.900 | |
| F | | | 7.1 | | | 0.280 |
| I | | | 3.93 | | | 0.155 |
| L | | 3.3 | | | 0.130 | |
| Z | | | 1.34 | | | 0.053 |



Ceramic DIP20 MECHANICAL DATA

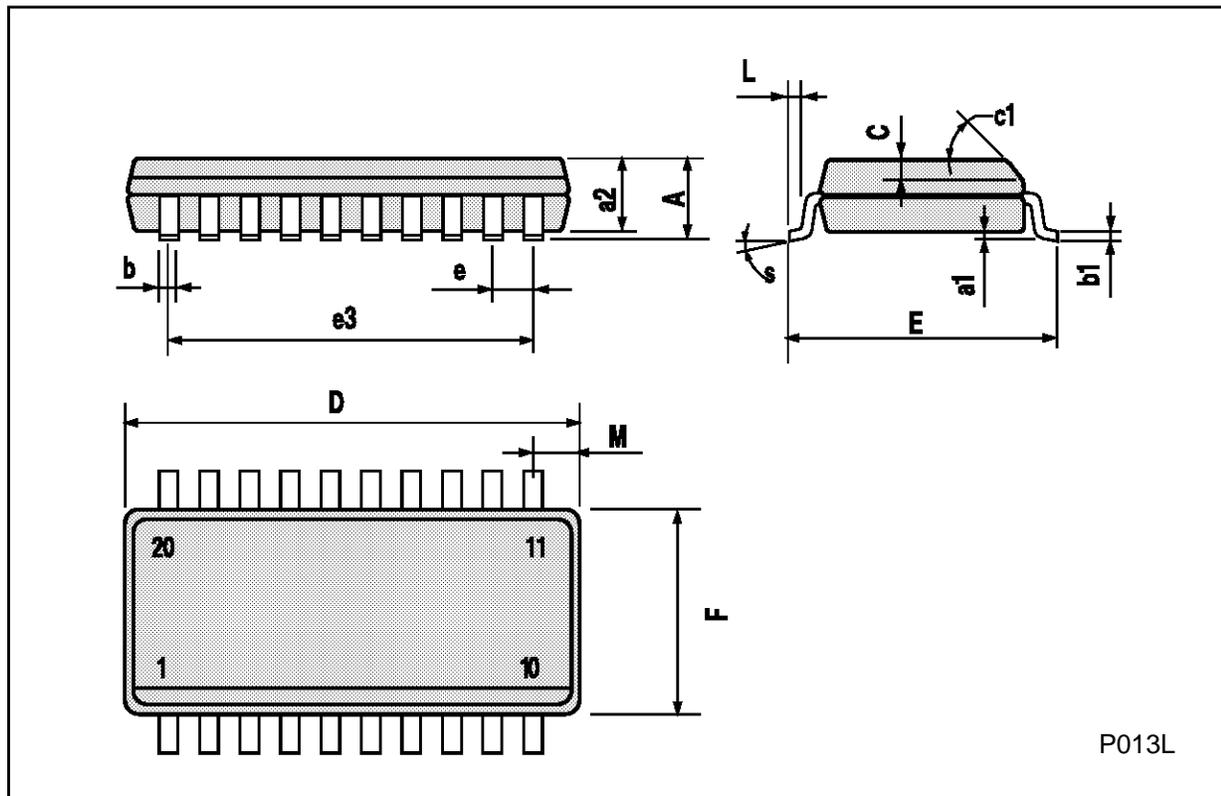
| DIM. | mm | | | inch | | |
|------|-----------------------|-------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 25 | | | 0.984 |
| B | | | 7.8 | | | 0.307 |
| D | | 3.3 | | | 0.130 | |
| E | 0.5 | | 1.78 | 0.020 | | 0.070 |
| e3 | | 22.86 | | | 0.900 | |
| F | 2.29 | | 2.79 | 0.090 | | 0.110 |
| G | 0.4 | | 0.55 | 0.016 | | 0.022 |
| I | 1.27 | | 1.52 | 0.050 | | 0.060 |
| L | 0.22 | | 0.31 | 0.009 | | 0.012 |
| M | 0.51 | | 1.27 | 0.020 | | 0.050 |
| N1 | 4° (min.), 15° (max.) | | | | | |
| P | 7.9 | | 8.13 | 0.311 | | 0.320 |
| Q | | | 5.71 | | | 0.225 |



P057H

SO20 MECHANICAL DATA

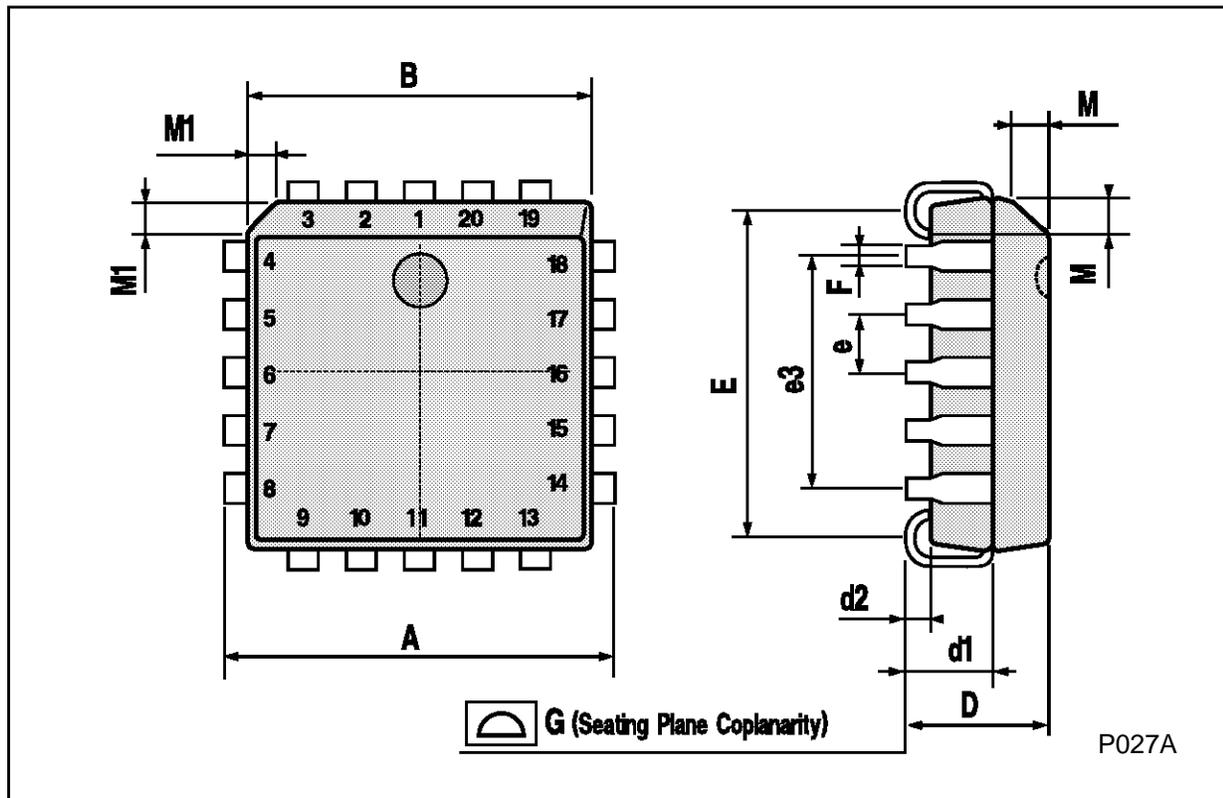
| DIM. | mm | | | inch | | |
|------|------------|-------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 2.65 | | | 0.104 |
| a1 | 0.10 | | 0.20 | 0.004 | | 0.007 |
| a2 | | | 2.45 | | | 0.096 |
| b | 0.35 | | 0.49 | 0.013 | | 0.019 |
| b1 | 0.23 | | 0.32 | 0.009 | | 0.012 |
| C | | 0.50 | | | 0.020 | |
| c1 | 45° (typ.) | | | | | |
| D | 12.60 | | 13.00 | 0.496 | | 0.512 |
| E | 10.00 | | 10.65 | 0.393 | | 0.419 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 11.43 | | | 0.450 | |
| F | 7.40 | | 7.60 | 0.291 | | 0.299 |
| L | 0.50 | | 1.27 | 0.19 | | 0.050 |
| M | | | 0.75 | | | 0.029 |
| S | 8° (max.) | | | | | |



P013L

PLCC20 MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|------|------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 9.78 | | 10.03 | 0.385 | | 0.395 |
| B | 8.89 | | 9.04 | 0.350 | | 0.356 |
| D | 4.2 | | 4.57 | 0.165 | | 0.180 |
| d1 | | 2.54 | | | 0.100 | |
| d2 | | 0.56 | | | 0.022 | |
| E | 7.37 | | 8.38 | 0.290 | | 0.330 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 5.08 | | | 0.200 | |
| F | | 0.38 | | | 0.015 | |
| G | | | 0.101 | | | 0.004 |
| M | | 1.27 | | | 0.050 | |
| M1 | | 1.14 | | | 0.045 | |



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